Tabelul 6a. Rezistoare discrete

Nr. crt.	Nume ref.	R_N	t [%]	PN [W]	[ppm/°C]	UN [V]	T _m [°C]	T _M [°C]	T _N [°C]	F [μV/V] sau NI [dB]	Riz [GΩ] sau Uiz [V]
1.	R1	150	±5%	1/16	±100	50	-55	+155	70	20	100
2.	R2	10k	±5%	1/10	±100	50	-55	+155	70	40	100
3.	R3	180	±5%	1/8	±100	150	-55	+155	70	20	300
4.	R4	220k	±5%	1/4	±100	200	-55	+155	70	46	400
5.	R5	10	±1%	1/2	±100	2.23	-55	+150	70	-	5.59
6.	R6	2.2k	±1%	3/4	±100	200	-55	+155	70	34	500
7.	R7	220	±5%	1	±100	200	-55	+155	70	24	500
8.	RC2	56k	±5%	1/4	-450	250	-55	+155	70	-	500
9.	RV1	15	±5%	1/4	N/A	250	-55	+125	70	-	400
10.	RV2	680k	±5%	0.5	N/A	250	-55	+125	70	-	400
11.	RM1	180k	±1%	0.6	±50	350	-55	+155	70	N/A	N/A
12.	RM2	15.8	±1%	0.6	±50	350	-55	+155	70	N/A	N/A
13.	ROX2	100	±5%	1	+350	350	-55	+155	70	N/A	500
14.	ROX3	10	±5%	3	+350	350	-55	+155	70	N/A	500
15.	RME1	1.1k	±1%	0.2	±50	150	-55	+125	70	-	N/A
16.	RME2	18k	-	0.25	-	200	-55	+125	70	-	N/A
17.	RME3	15k	±1%	0.4	±50	300	-55	+125	70	-	N/A
18.	RW3	6.8	±5%	5	+200	350	-55	+155	70	N/A	1000
19.	RW4	0.68	±5%	7	+200	500	-55	+155	70	N/A	1000
20.	RCW2	12	±5%	2.5	+200	100	-55	+155	70	N/A	350
21.	RCW3	100	±5%	4.3	+200	150	-55	+155	70	N/A	500

Tabelul 6b. Rezistoare integrate - rețele rezistive

Nr. crt	Nume ref.	Aranjare rezistoare în capsulă	R1 [Ω]	R2 [Ω]	t[%]	PN capsulă [W]	PN rezistor [W]	α [ppm/°C]	VN [V]	T _m [°C]	T _M [°C]	T _N [°C]	Riz [GΩ] sau Uiz [V]
1	RN1	Dual	200	330	±2%	1	0.2	±100	100	-55	+125	70	200
		terminator											
2	RN2	Isolated	100	-	±2%	2.25	0.25	±100	100	-55	+125	70	200
3	RN3	Isolated	4.7k	-	±2%	1.12	0.16	±100	50	-55	+125	70	200